

RoHS Compliant Product
A suffix of "-C" specifies halogen & lead-free

FEATURES

- Simplifies Circuit Design
- We Declare that the material of product compliance with RoHS requirements

MARKING

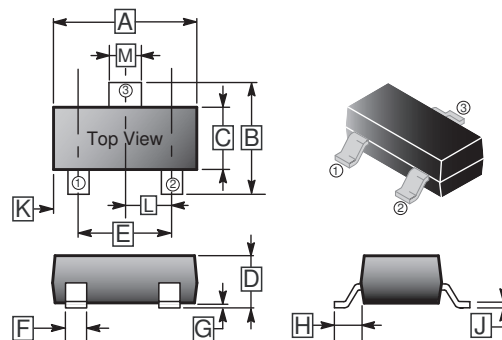
1N

AM

PACKAGE INFORMATION

Package	MPQ	Leader Size
SOT-523	3K	7 inch

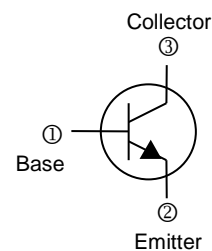
SOT-523



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	1.50	1.70	G	-	0.10
B	1.45	1.75	H	0.55	REF.
C	0.70	0.90	J	0.08	0.20
D	0.60	0.90	K	-	-
E	0.90	1.10	L	0.50	TYP.
F	0.15	0.35	M	0.25	0.40

ORDER INFORMATION

Part Number	Type
MMBT3904FW-C	Lead (Pb)-free and Halogen-free



MAXIMUM RATINGS (T_A=25°C unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Collector-Base Voltage	V _{CB0}	60	V
Collector-Emitter Voltage	V _{CEO}	40	
Emitter-Base Voltage	V _{EBO}	6	
Continuous Collector Current	I _c	200	mA
Total Device Dissipation FR-4 Board ¹	T _A =25°C	200	mW
	Derate above 25°C	1.6	mW/°C
Thermal Resistance, Junction-Ambient	R _{θJA}	600	°C/W
Total Device Dissipation FR-4 Board ²	T _A =25°C	300	mW
	Derate above 25°C	2.4	mW/°C
Thermal Resistance, Junction-Ambient	R _{θJA}	400	°C/W
Junction & Storage Temperature Range	T _J , T _{STG}	-55~150	°C

Notes:

1. FR-4 Minimum Pad.
2. FR-4 1.0 X 1.0 Inch Pad.
3. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Min.	Max.	Unit	Test conditions
Collector-Emitter Breakdown Voltage ¹	$V_{(BR)CEO}$	40	-	V	$I_C=1\text{mA}, I_B=0$
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	60	-	V	$I_C=10\mu\text{A}, I_E=0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	6	-	V	$I_E=10\mu\text{A}, I_C=0$
Collector Cut-off Current	I_{BL}	-	50	nA	$V_{CE}=30\text{V}, V_{EB}=3\text{V}$
Emitter Cut-off Current	I_{CEX}	-	50	nA	$V_{CE}=30\text{V}, V_{BE}=3\text{V}$
DC Current Gain ¹	h_{FE}	40	-		$I_C=0.1\text{mA}, V_{CE}=1\text{V}$
		70	-		$I_C=1\text{mA}, V_{CE}=1\text{V}$
		100	300		$I_C=10\text{mA}, V_{CE}=1\text{V}$
		60	-		$I_C=50\text{mA}, V_{CE}=1\text{V}$
		30	-		$I_C=100\text{mA}, V_{CE}=1\text{V}$
Collector-Emitter Saturation Voltage ¹	$V_{CE(sat)}$	-	0.2	V	$I_C=10\text{mA}, I_B=1\text{mA}$
		-	0.3		$I_C=50\text{mA}, I_B=5\text{mA}$
Base-Emitter Saturation Voltage ¹	$V_{BE(sat)}$	0.65	0.85	V	$I_C=10\text{mA}, I_B=1\text{mA}$
		-	0.95		$I_C=50\text{mA}, I_B=5\text{mA}$
Current-Gain-Bandwidth Product	f_T	200	-	MHz	$V_{CE}=20\text{V}, I_C=10\text{mA}, f=100\text{MHz}$
Output Capacitance	C_{obo}	-	4	pF	$V_{CB}=5\text{V}, I_E=0, f=1\text{MHz}$
Input Capacitance	C_{ibo}	-	8	pF	$V_{BE}=0.5\text{V}, I_E=0, f=1\text{MHz}$
Input Impedance	h_{ie}	1	10	pF	$V_{CE}=10\text{V}, I_C=1\text{mA}, f=1\text{kHz}$
Voltage Feedback Ratio	h_{re}	0.5	8	$\times 10^{-4}$	$V_{CE}=10\text{V}, I_C=1\text{mA}, f=1\text{kHz}$
Small-Signal Current Gain	h_{fe}	100	400		$V_{CE}=10\text{V}, I_C=1\text{mA}, f=1\text{kHz}$
Output Admittance	$*h_{oe}$	1	40	μmhos	$V_{CE}=10\text{V}, I_C=1\text{mA}, f=1\text{kHz}$
Noise Figure	NF	-	5	dB	$V_{CE}=5\text{V}, I_C=100\mu\text{A}, R_S=1\text{k}\Omega, f=1\text{kHz}$
Delay Time	t_d	-	35	nS	$V_{CC}=3\text{V}, V_{BE}=0.5\text{V}, I_C=10\text{mA}, I_{B1}=1\text{mA}$
Rise Time	t_r	-	35		
Storage Time	t_s	-	200	nS	$V_{CC}=3\text{V}, I_C=10\text{mA}, I_{B1}=I_{B2}=1\text{mA}$
Fall Time	t_f	-	50		

Note:

1. Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.

CHARACTERISTIC CURVES

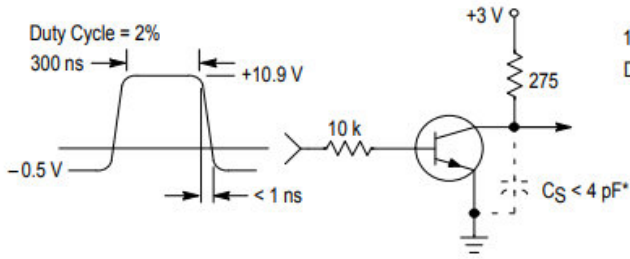


Figure 1. Delay and Rise Time Equivalent Test Circuit

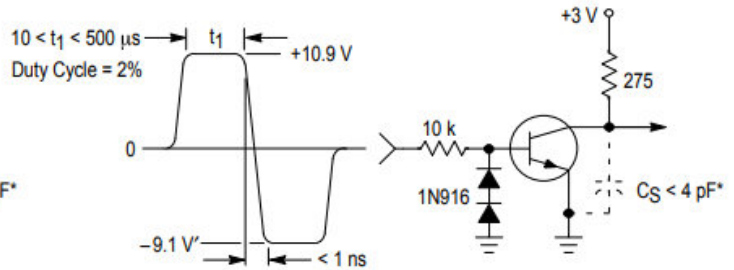


Figure 2. Storage and Fall Time Equivalent Test Circuit

* Total shunt capacitance of test jig and connectors

TYPICAL TRANSIENT CHARACTERISTICS

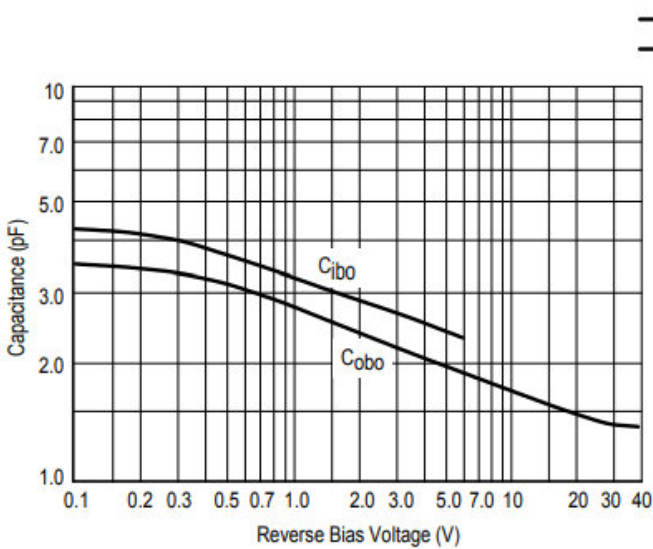


Figure 3. Capacitance

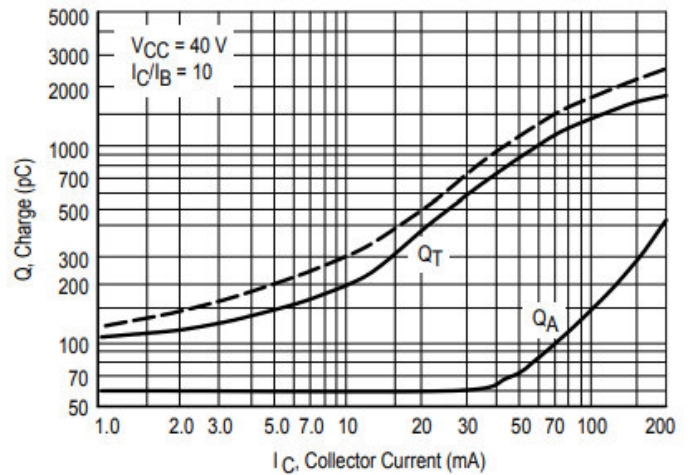


Figure 4. Charge Data

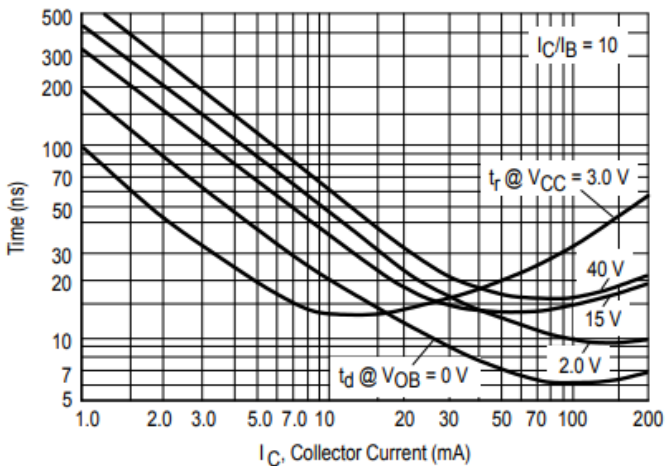


Figure 5. Turn-On Time

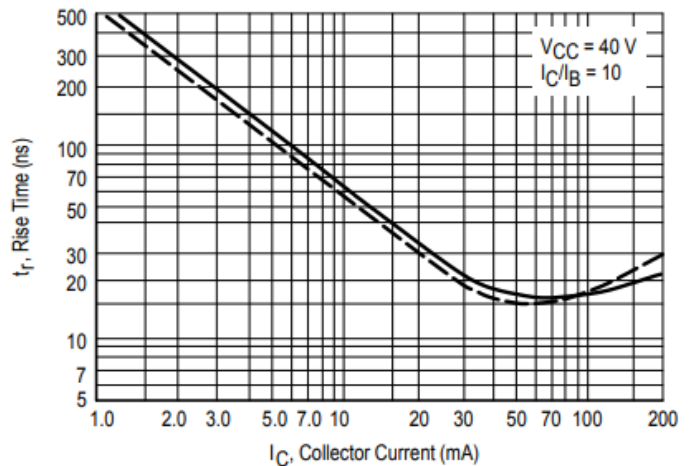


Figure 6. Rise Time

CHARACTERISTIC CURVES

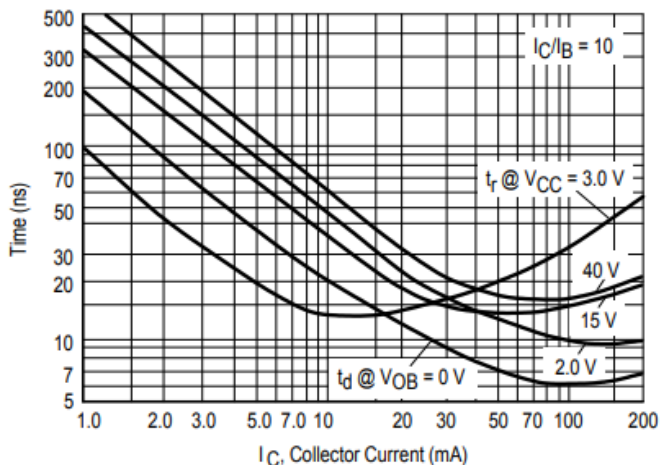


Figure 5. Turn-On Time

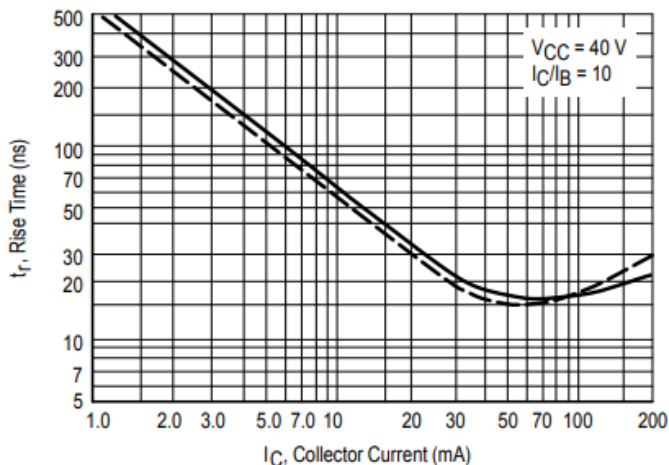


Figure 6. Rise Time

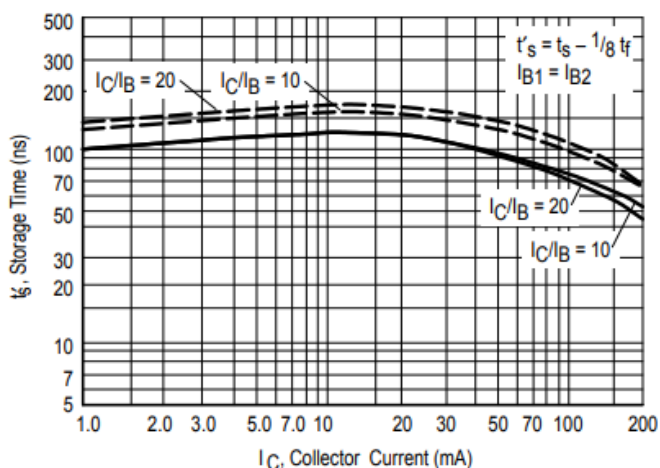


Figure 7. Storage Time

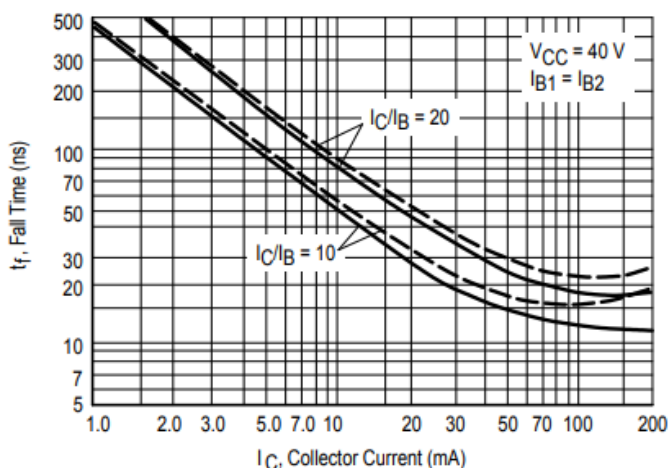


Figure 8. Fall Time

**TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS
NOISE FIGURE VARIATIONS**

(VCE = 5.0 Vdc, TA = 25°C, Bandwidth = 1.0 Hz)

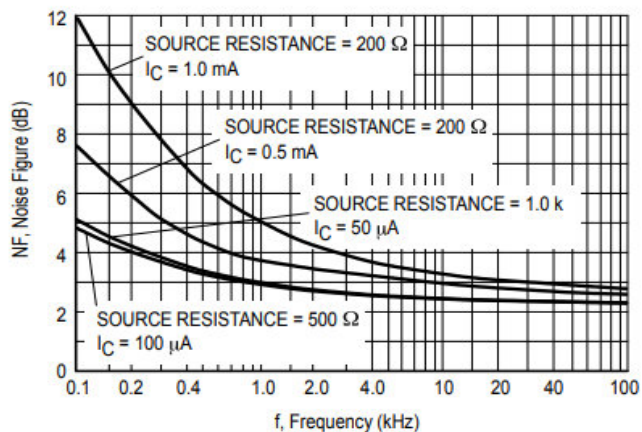


Figure 9.

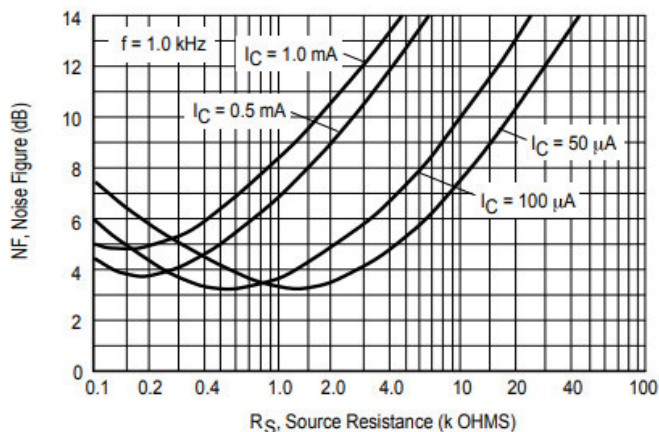


Figure 10.

CHARACTERISTIC CURVES

h PARAMETERS
($V_{CE} = 10\text{ Vdc}$, $f = 1.0\text{ kHz}$, $T_A = 25^\circ\text{C}$)

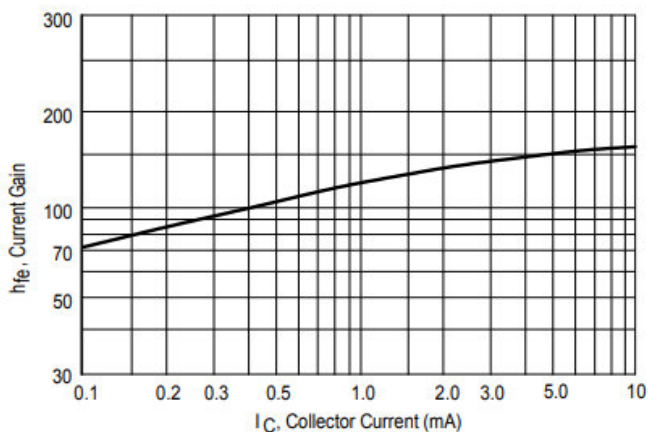


Figure 11. Current Gain

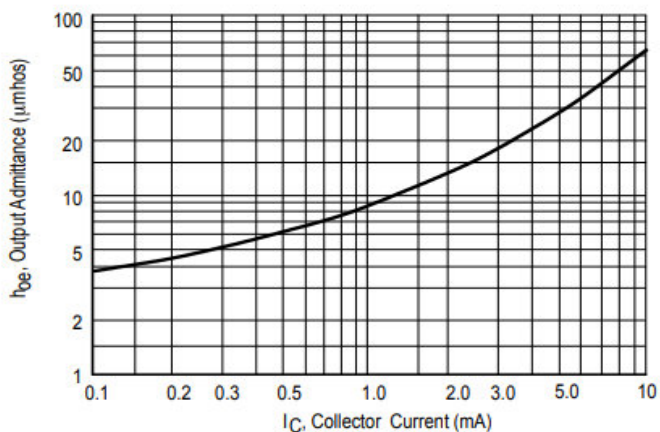


Figure 12. Output Admittance

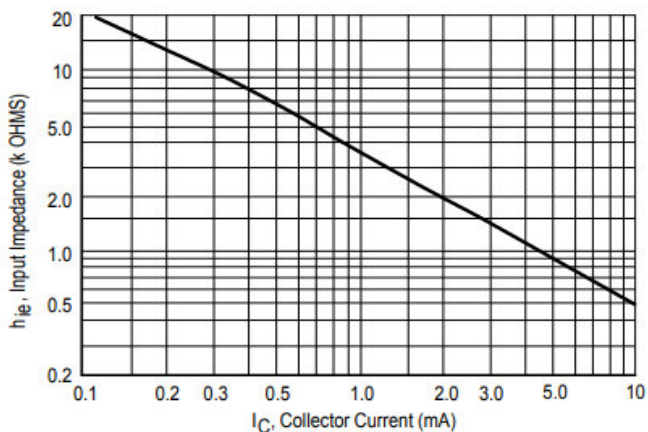


Figure 13. Input Impedance

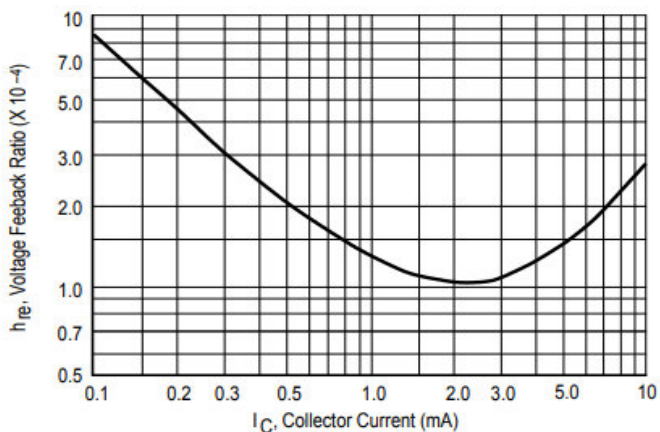


Figure 14. Voltage Feedback Ratio

TYPICAL STATIC CHARACTERISTICS

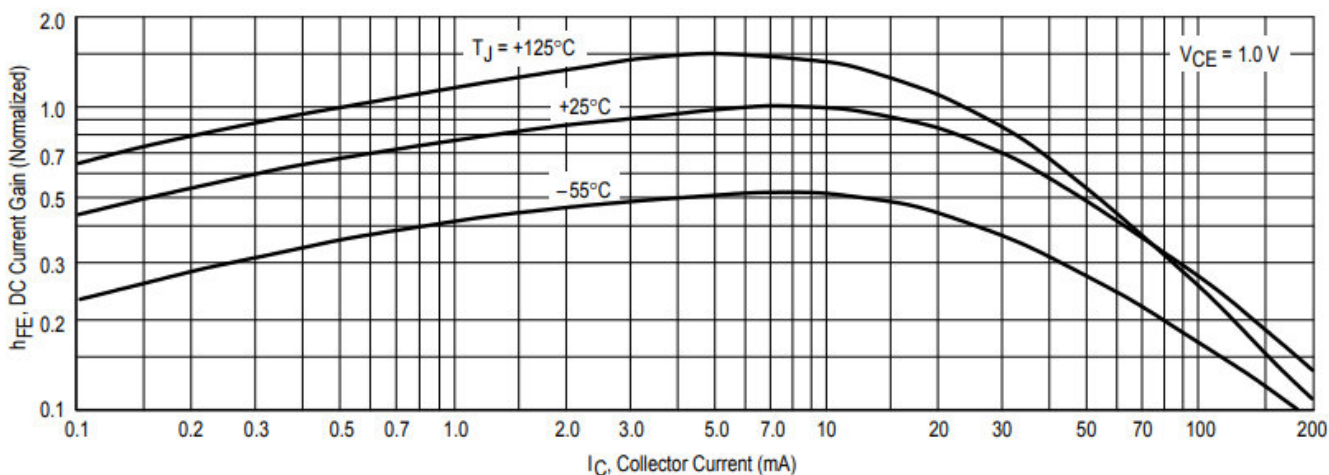


Figure 15. DC Current Gain

CHARACTERISTIC CURVES

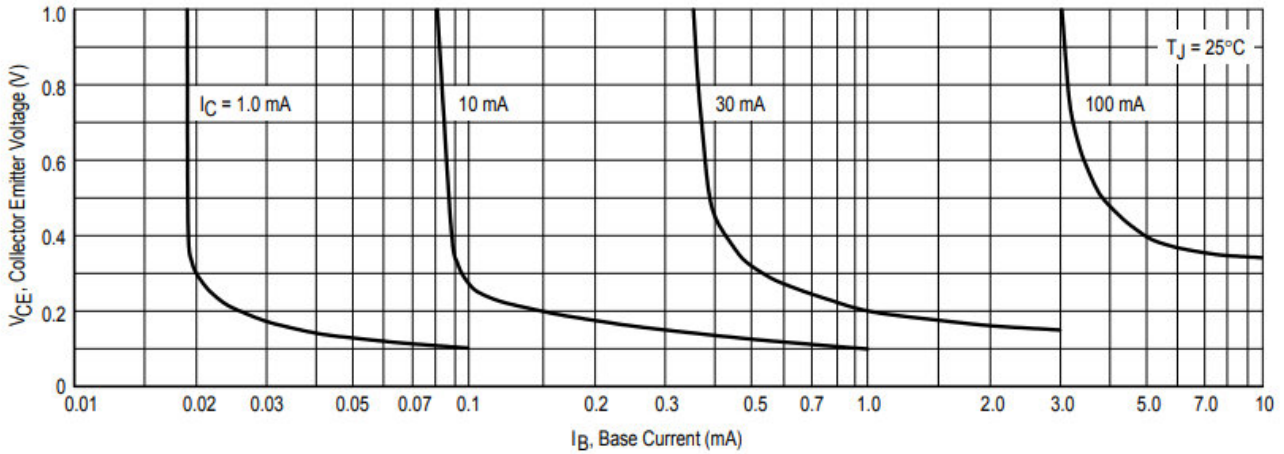


Figure 16. Collector Saturation Region

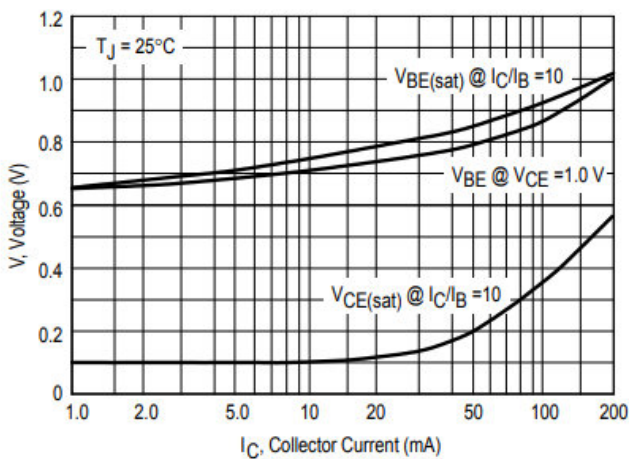


Figure 17. "ON" Voltages

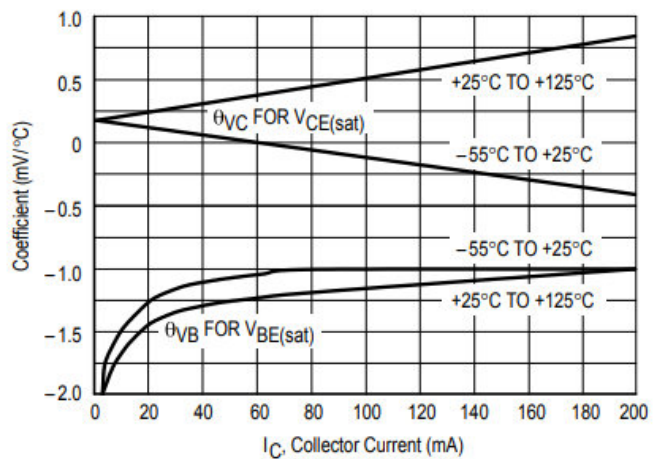
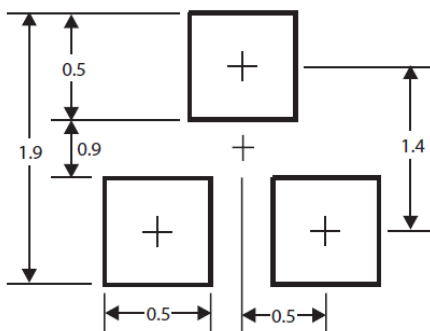


Figure 18. Temperature Coefficients



*Dimensions in millimeters

Figure 19. Mounting Pad Layout